



## Atomic Scale Structure of Liquid Metal - Electrolyte Interfaces

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ARTICLE

## Atomic Scale Structure of Liquid Metal - Electrolyte Interfaces

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Electrochemical interfaces between immiscible liquids lately receive renewed interest, both for fundamental insight as well as for applications in nanomaterial synthesis. In this feature article we demonstrate that the atomic scale structure of these previously inaccessible interfaces nowadays can be explored by *in situ* synchrotron based X-ray scattering techniques. Exemplary studies of a prototypical electrochemical system – the liquid mercury electrode in pure NaCl solution – reveal that the liquid metal is terminated by a well-defined atomic layer. This layering decays on lengths scales on 0.5 nm into the Hg bulk and displays a potential and temperature dependent behaviour that can be explained by electrocapillary effects and contributions of the electronic charge distribution on the electrode. In similar studies of nanomaterial growth, performed for the electrochemical deposition of PbFBr, a complex nucleation and growth behaviour is found, involving a crystalline precursor layer prior to 3D crystal growth. *Operando* X-ray scattering measurements provide detailed data on the processes of nanoscale film formation.

### Introduction

From the end of the 1800's on and throughout the last century, liquid metals and in particular the liquid Hg - electrolyte interface have played a key role in the development of the theory of the electrical double layer and electrochemical adsorption<sup>1-5</sup>. The liquid Hg electrode represents the earliest example of an electric potential induced variation in an interface property, namely the interfacial tension, an effect known as electrocapillarity<sup>3,6,7</sup>. Hg electrodes have also been instrumental in key experiments verifying traditional<sup>1-3</sup> and modern<sup>4;5</sup> theories of the electrochemical double layer and have been used in a wide range of electrochemical studies including electrodeposition<sup>8</sup>, charge transfer<sup>9</sup> and chemical analytics<sup>9</sup>.

Interest in electrochemical liquid-liquid interfaces has increased again in recent years, coming from various directions. Extensive studies have been performed on interfaces between two immiscible electrolyte solutions (ITIES), focusing on ion and electron transfer<sup>10;19</sup>. Simultaneously to these experimental efforts molecular simulation studies have started to address the liquid-liquid interface structure<sup>11-13</sup>. Despite the lack of long-range order, liquid-liquid interfaces exhibit characteristic well-defined

structures, which need to be determined for better understanding of the interface processes. The most important structural property of liquid-liquid interfaces is the density profile across the interface, which is linked with the interface width, the chemical composition of the liquids near the interface (e.g., segregation or depletion of species) and more complex phenomena, such as molecular layering (Fig. 1). Furthermore, as for any fluid interface dynamic effects have to be taken into account, specifically the presence of thermally excited surface waves ("capillary waves"). The presence of these waves result in an average mean-square displacement of the interface  $\sigma_{CW}^2 = k_B T / 2\pi\gamma \cdot \ln(q_{min}/q_{max})$ , i.e. is determined by the interface tension  $\gamma$  and the range of wave-vectors  $q_{min}$  to  $q_{max}$ , which are given by the length scales where gravitational effects take over and the size of the molecules, respectively<sup>14</sup>. It is an open question whether the conventional theoretical treatment of these capillary waves within a continuum model describes the interface roughness down to the molecular scale<sup>10</sup>.

Beside fundamental insight these systems are of relevance to biomembrane studies and, in particular, of interest for material synthesis. A large variety of nanomaterials has been prepared via electrochemical and electroless deposition at liquid-liquid interfaces, including metals<sup>15</sup>, oxides<sup>16;17</sup> chalcogenides<sup>18;19</sup>, polymers<sup>20;21</sup> and plasmonic materials []. Studies of electrodeposition at electrified liquid - liquid interfaces have revealed conditions for inhibiting and enhancing growth of Au<sup>22;23</sup>, Pt and Pd nanoparticles<sup>10;24;25</sup>. In a similar way interest in the liquid Hg - electrolyte interface has renewed. As demonstrated by Maldonado and coworkers, deposition at liquid-liquid interfaces even allows the growth of nanostructured crystalline semiconductors such as Ge, Si and

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GaAs from oxide materials via a simple one-step, room-temperature electrochemical process<sup>26-29</sup>.

Despite the extensive work in these areas still very little is known about the precise structure of liquid-liquid interfaces and electrochemical processes at these phase boundary. In contrast to solid-liquid interfaces where detailed atomic-scale data has been obtained by a variety of microscopic, spectroscopic and synchrotron based *in situ* techniques, accessing atomic scale information on liquid-liquid remains a major experimental challenge. For a long time understanding of the structure of liquid-liquid interfaces had to rely on traditional electrochemical measurements, such as interface tension, capacitance and chronocoulometry. Although these methods can provide some insight, e.g. the surface excesses of adsorbed species, they do not allow determination of the atomic arrangement at the interface. This also holds true for more advanced probes, such as spatial scanning spectro-electrochemistry<sup>30</sup>, which likewise reveal only macroscopic properties of the interface. Surface X-ray scattering methods uniquely can deliver such data - even for interfaces between two extended immiscible liquid phases - *in situ* and *operando* with atomic-scale resolution. This was realized as early as in the 1990ies<sup>31</sup>; however, X-ray investigations of these deeply buried interfaces were hampered by experimental challenges that make these measurements by far more challenging than X-ray scattering studies of solid-liquid electrodes. These difficulties include mechanical stability, high X-ray absorption and background and the problem that the sample cannot be tilted, requiring specialized X-ray diffractometers. Only in recent years atomic scale structural studies of these elusive interfaces have emerged, made possible by recent developments in synchrotron radiation sources capable of delivering X-ray beams of high photon energies and high brilliance<sup>22;31-36</sup>. In the following, we will discuss the experimental approaches employed for X-ray scattering of liquid-liquid interfaces and present exemplarily studies of the structure of the liquid metal - electrolyte interface that illustrate the level of structural detail obtainable by these measurements.

## X-ray scattering from liquid-liquid interfaces

A key technique in the study of fluid interfaces is X-ray reflectivity (XRR) as it can assess the molecular scale interface structure even in the absence of long-range order. XRR measures the intensity fraction  $R(q_z)$  of an X-ray beam of wavelength  $\lambda$  impinging onto the interface at angle  $\alpha$  and reflected at angle  $\beta = \alpha$ , respectively. Here,  $q_z = (4\pi/\lambda) \cdot \sin\alpha$  is the magnitude of the scattering vector, which in reflectivity measurements is oriented along the surface normal. The background, resulting from scattering by the bulk liquids, may be measured by offsetting the detector out of the plane of reflection, and subtracted from the specular signal. Due to the rapid decay of  $R(q_z)$  with increasing  $q_z$  the reflected X-ray intensity has to be measured over 7 to 9 orders of magnitude. The reflectivity provides

direct access to the total electron density profile across the interface region. For most liquid interfaces  $R$  is well described by the Master equation<sup>37</sup>, which states that  $R(q_z)$  is the Fresnel reflectivity  $R_F(q_z)$  of a perfectly sharp interface, multiplied by the square of the Fourier transform of the gradient  $d\langle\rho_e(z)\rangle/dz$ , where  $\langle\rho_e(z)\rangle$  is the total electron density averaged within the surface plane. For a single component liquid composed of heavier atoms  $\rho_e$  is dominated by the contributions of the ion cores and  $\langle\rho_e(z)\rangle$  closely resembles the atomic distribution along the surface normal  $\langle\rho(z)\rangle$  (convoluted by the radial electron density distribution function of the atoms). Typically, reflectivity measurements start at angles below the critical angle  $\alpha_c$  of total external reflection of the X-ray beam, which is in the range of a few tenth of a degree at most. Under these conditions the beam is spread out over a centimetre of the sample within the reflection plane, requiring an extended planar interface area.

Experimental studies of liquid interfaces provide many challenges. One of the biggest is the need for deflecting the X-ray beam down on the (horizontal) interface. For experiments at synchrotron sources this requires dedicated liquid surface diffractometers with deflection optics. Liquid diffractometer designs similar to that by Als-Nielsen and Pershan<sup>37-43</sup> achieve this by employing the Bragg reflection of a single crystal that is rotated around the axis of the incoming horizontal X-ray beam. The Bragg-reflected beam moves on the surface of a cone with the tip at the deflecting optics. Therefore both the sample and the detector have to be moved vertically and horizontally to follow the beam, as illustrated schematically in Fig. 2a. An alternative, more recent approach employs a more complex setup, where the incoming X-ray beam is scattered upwards via reflection at a first crystal with a Bragg angle  $\theta_1$  and then bent downward again using a second crystal with a larger Bragg angle  $\theta_2$ , defining a plane in which the beam is located (Fig. 2b)<sup>44-47</sup>. The sample is placed at the intersection of this beam plane with a horizontal plane defined by the incoming beam at angle of incidence  $\alpha = 0$  ("sample plane"). The sample's interface is positioned in the sample plane and the centre of the sample located at the intersection of the original incoming beam axis (dashed line) with the twice deflected beam. By rotating the crystals around the incoming beam axis the angle of incidence  $\alpha$  can be varied from 0 to a maximum angle  $\alpha_{\max} = 2(\theta_2 - \theta_1)$ . A detailed introduction into scattering from liquid interfaces is provided by the excellent book by Pershan and Schlossman<sup>48</sup>.

For studies of liquid-liquid interfaces the experimental challenges are even greater. Here the liquids have to be confined in a cell with the lower density liquid stacked on top of the denser one and the X-ray beam entering and leaving the cell through (glass) windows (Fig. 2c). Because curvature of the liquid meniscus at the cell wall cannot be avoided, the requirement of a sufficiently large planar interface entails a cell diameter of several centimetres. This leads to huge X-ray absorption losses and substantially enhanced background scattering from both liquids. In practice, hard X-rays with photon energies above 18 keV are necessary to penetrate the liquid environment. The same problems occur in studies by other surface scattering techniques, such as measurements of the

diffuse interface scattering or studies of the in-plane interface structure by scattering under grazing incident angles.

The results obtained in the following were obtained at the liquid surface diffractometer at beam line ID-9 of the Advanced Photon Source at Argonne National Laboratory and at the Liquid Interfaces Scattering Apparatus (LISA), installed at beamline P08 of the PETRAIII synchrotron source at DESY. The former uses the single crystal deflection scheme, making waiting times of 15 s necessary after each angle change to allow mechanical excitations of the surface to die down. The LISA diffractometer has pioneered the double crystal design in Bragg reflection geometry and allows measurements of an immobile, mechanically completely decoupled sample, providing high mechanical stability of the liquid interface. Both instruments allow studies at photon energies  $> 20$  keV and surface-normal wave vector transfers  $q_z > 2.5 \text{ \AA}^{-1}$ .

### Liquid metal - electrolyte interface

Atomic scale insight into liquid metal electrodes was first gained in studies of the structure of the free liquid surface in contact with a gas phase. Theory predicted that the metal-vapour interface should result in strong atomic layering in contrast to the monotonic behaviour displayed by dielectric liquids.<sup>49</sup> This is due to sudden decrease in density of the conduction electrons at the conducting liquid - insulating vapour interface<sup>50;51</sup>. Experimentally, this layering behaviour was observed first in XRR measurements at the surface of Hg<sup>14;52</sup> and later found for other liquid metals such as gallium<sup>53</sup>, indium<sup>44</sup>, potassium<sup>54;55</sup>, tin<sup>56;57</sup>, bismuth<sup>56;57</sup> and selected alloys<sup>36;58;59</sup>. In the XRR data surface layering manifests as a distinct quasi-Bragg peak which occurs at a momentum transfer position  $q_z \approx 2/\sqrt{3}r$ , i.e. is roughly determined by the atomic radius  $r$  of the metal. In the case of Hg  $q_z = 2.2 \text{ \AA}^{-1}$ <sup>52</sup> and  $r = 1.60 \text{ \AA}$ . In contrast to the layer spacing which was found to be independent of temperature  $T$ , the surface roughness increased sharply with increasing  $T$ <sup>14</sup>. Although an increase in the capillary wave roughness with temperature is expected, Hg is unique in exhibiting an increase greater than the  $\sigma_{CW} \sim \sqrt{T/\gamma}$  dependence predicted by capillary wave theory.

In a first atomic resolution *in situ* XRR study of the liquid metal - electrolyte interface, liquid Hg electrodes in a 0.1 M NaF solution were investigated<sup>34</sup>. The reflectivity was collected out to  $q_z = 2.5 \text{ \AA}^{-1}$  (Fig. 3). The reflected signal at the expected detector angle  $\beta = \alpha$  could be clearly separated from the high background scattering by the Hg and electrolyte bulk liquids (inset), allowing measurements of  $R(q_z)$  over seven orders of magnitude. Similar as at the liquid Hg - vapour interface, a quasi-Bragg peak was observed at  $2.15 \text{ \AA}^{-1}$ . This indicates distinct layering of the Hg atoms near the surface of the liquid Hg electrode, as illustrated in Fig. 1. The intensity of the layering peak varied with applied potential and had a maximum at 0.3 V vs. the potential of zero charge (pzc),

whereas the layering peak's position was potential independent.

Recalling that  $R/R_F$  is related to the laterally averaged surface normal electron density profile  $\langle \rho_e(z) \rangle$ , it is possible to quantitatively model the profile across the interface. The standard description of liquid metal layering is provided by the distorted crystal model (DCM)<sup>52;60;61</sup>. In this model  $\langle \rho_e(z) \rangle$  is described by an infinite stack of atomic layers with equal spacing  $d$  and a Gaussian width  $\sigma_n = \sqrt{n\sigma_b^2 + \sigma_i^2}$ , which has two contributions:  $\sigma_i$  is an intrinsic width, common to all layers, and  $\sigma_b$  characterizes the broadening and hence the decay of the layering with depth  $nd$ . For the Hg - NaF interface this model gave layer spacing and decay lengths similar to those found for the Hg vapour interface<sup>29</sup>.

Very recently, more detailed studies of the atomic-scale Hg - electrolyte interface structure as a function of temperature and potential were performed that employed a combination of XRR and measurements of the X-ray diffuse scattering (XDS) from the Hg surface<sup>62</sup>. XDS gives information on the lateral distribution of the interface roughness, more precisely, the height-height correlation function of the interface<sup>63</sup>. Because it is orders of magnitudes lower than the reflectivity, XDS measurements at liquid-liquid interfaces are particular challenging. A characteristic example of XDS data for the Hg electrolyte interface is shown in Fig. 4a. The shape of the central peak at  $\beta = 0.012$  rad is dominated by the specular reflectivity; the gradual decay of the intensity at higher and lower reflection angles is determined by the roughness due to surface waves and exhibits a power law dependence as expected from capillary wave theory<sup>64;65</sup>. Also visible are the Yonada wings occurring at the position where the scattered beam angle  $\beta$  is equal to the critical angle  $\alpha_c$ . Quantitative analysis of the XDS measurements showed that (within the experimental errors) the capillary wave roughness was in good agreement with the interface tension  $\gamma(\phi, T)$  for the Hg electrode in 0.01 M NaF<sup>3;66</sup>. Specifically,  $\gamma(\phi, T)$  extracted from the XDS data exhibited a roughly parabolic potential dependence as expected from the electrocapillary effect (Fig. 4b, top panel)<sup>34;36</sup>. Because the XDS measurements were limited by the signal-to-background ratio to lateral wave vector transfers  $q_{xy} \leq 10^{-3} \text{ \AA}^{-1}$ , i.e. capillary waves with wavelengths above 100 nm, the good agreement with a theory employing a continuum model is not surprising. Deviations are only expected upon approaching atomic length scales, as indeed has been reported in XDS studies of the free surface of water<sup>67;68</sup>. For liquid-liquid interfaces such studies are currently not possible. Nevertheless, deviations from classic capillary wave theory will influence the interface roughness and thus may contribute to the layer widths in the electron density profiles<sup>69</sup>.

To obtain better insight into the interface structure on nanometer length scales the capillary wave contribution was removed and the resulting total electron density profile was deconvoluted by the electron density distribution within the

Hg atoms<sup>70</sup> (i.e. the Fourier transform of the Hg atomic form factor). This procedure leads to profiles that largely reflect the atomic distribution of the Hg atoms in surface normal direction ( $\langle\rho(z)\rangle$ ), which more clearly reveal the substantial changes in interface structure with potential and temperature (Fig. 4c). The results favour a model where the structural parameters of the Hg surface layer significantly differ from those of the subsequent layers underneath. In particular, the spacing between the topmost and the second Hg layer is smaller than the average layer spacing  $d$ . This resembles the tendency of surface layers on crystalline metal surfaces to undergo reconstruction or inward relaxation and is also supported by theoretical work on liquid metal surfaces<sup>70</sup>. At 4° C the layer spacing  $d$  and the layer density are close to those of the (111) planes in crystalline Hg ( $d_{(111)} = 2.62 \text{ \AA}$ ) and the intrinsic width of the Hg surface layer is only 0.2 to 0.4 Å. The observations indicate that the surface of the liquid metal electrode is well-defined and close-packed on the atomic scale, as has been assumed in previous theoretical studies<sup>71</sup>.

Based on a detailed analysis of the potential and temperature dependence, several characteristic effects were found<sup>69</sup>: First, a temperature dependent roughness anomaly known from the Hg-air interface<sup>14</sup> persisted also at the Hg-electrolyte interface. Additionally, the layering period substantially increased with temperature. This increase was a factor four larger than the Hg thermal expansion coefficient and may be caused by the thermal broadening of the atomic layers. Secondly, the interface is found to slightly broaden towards the electrolyte side as the potential becomes more negative (Fig. 4c). This effect may be related to the contribution of the conduction electrons to the X-ray scattering rather than to the distribution of the Hg ion cores. According to the Schmickler-Henderson theory of the Helmholtz capacitance, the conduction electron distribution at the interface is polarized by the strong electric field of the electrochemical double layer<sup>72</sup>. The quantitative predictions for the magnitude of this effect at Hg electrodes are in good agreement with the changes observed in the XRR studies.

In addition to these studies of Hg electrodes in non-specifically adsorbing electrolyte XRR measurements of liquid Hg in highly concentrated solutions containing chemisorbing ions were performed by Duval et al.<sup>35</sup>. In these studies the Hg layering peak was weaker and depended much more strongly on potential than found in NaF solution, indicating a strong influence of ion presence on Hg layering. Furthermore, a pronounced second peak at  $q_z$  values around  $1.5 \text{ \AA}^{-1}$  was observed, associated with an additional layer on the Hg surface. Surface excesses derived from the XRR data deviated strongly (even in sign) from those obtained by traditional electrochemical measurements. This was assigned to the contribution of a partial layer of Hg atoms at the interface that varied its composition as a function of voltage, nature of the ions and the chemical environment. However, it is not clear whether these results may in part be affected by the unusual

electrochemical conditions employed in these measurements. More detailed studies employing different (in particular lower) concentrations and a supporting electrolyte seem necessary to verify this behaviour.

## Growth at liquid Metal electrolyte interfaces

Exciting developments in material synthesis have recently renewed interest in immiscible liquid - liquid interfaces as a template for growth<sup>15</sup>. Unlike solid interfaces, where strain and stress, heterogeneities, and defects strongly influence growth processes, fluid systems provide soft, defect- and stress-free interfaces. The growth process in liquid phases profits from the high mobility of atoms, molecules, and deposited particles as well as the self-assembly of ordered particle arrays at the interface.

Atomic scale studies of electrochemical induced nucleation and growth at a liquid-liquid interface were performed by *in situ* X-ray scattering methods for liquid Hg electrodes in electrolyte solutions containing  $\text{Pb}^{2+}$ ,  $\text{F}^-$ , and  $\text{Br}^-$  ions<sup>36</sup>. In this electrolyte Pb amalgamation occurs at potentials negative of  $-0.70 \text{ V}_{\text{Hg}/\text{Hg}_2\text{SO}_4}$  (see cyclic voltammogram in Fig. 5b). XRR studies in this regime (Fig. 5a) are identical to those in pure NaF solution, indicating the characteristic surface-layered structure of a clean Hg surface. Apparently, the deposited Pb atoms are dissolved in the Hg bulk and do not exhibit a tendency towards surface aggregation. Upon inducing the release of  $\text{Pb}^{2+}$  by stepping the potential to values positive of the amalgamation potential substantial changes in the reflectivity  $R(q_z)$  emerge. In particular, pronounced oscillations are found, heralding the formation of an intriguing interface structure with a well-defined 7.6 Å-thick adlayer. In addition, the observation of Bragg reflections indicates the nucleation and growth of structurally related 3D crystallites on top of this adlayer (Fig. 5c), which are identified as  $\text{PbFBr}$ , preferentially aligned with the  $\vec{c}$  axis along the interface normal. Quantitative analysis of the XRR data shows the adlayer to consist of a stack of five ionic layers, forming a single-unit-cell-thick crystalline  $\text{PbFBr}$  precursor film with (001) orientation. Because of the structural rigidity of this ultrathin crystalline layer, the capillary waves of the interface are substantially damped, resulting in a decrease in the interface roughness and a concomitant increase in intensity at higher  $q_z$ .

The surprising formation of a film of defined thickness, consisting of a full unit cell with five atomic layers of different ionic composition, can be explained by the combination of electrostatic and short range chemical interactions (Fig. 5c). In the dealgamation regime the Hg surface is covered by an adlayer of adsorbed  $\text{Br}^-$  anions, on which the released  $\text{Pb}^{2+}$  cations coadsorb. For electrostatic reasons subsequent adsorption of oppositely charged ionic layers is required until full charge neutrality is achieved. The latter occurs only upon completing a full unit cell, because the charge density per unit area of the  $\text{Pb}^{2+}$  and  $\text{F}^-$  layers is twice that of the  $\text{Br}^-$  layers. The

formation of simpler compounds consisting of fewer layers, e.g.,  $\text{PbBr}_2$ , is energetically less favourable due to the higher Gibbs enthalpy as compared to  $\text{PbFBr}$ <sup>73</sup>. The precursor layer formation resembles the formation of mixed salt-like layers found in underpotential deposition processes on solid electrode surfaces; however, the adlayers in that case only consisted of anion/cation bilayers.

The 3D crystals of  $\text{PbFBr}$  deposited on top of the precursor film are likewise (001)-oriented, suggesting that the initial layer acts as a template for subsequent quasiepitaxial growth. The potential-dependent kinetics of this growth process and of the dissolution of the  $\text{PbFBr}$  deposit were monitored in recent potential step experiments. Using a 2D X-ray detector the specular reflectivity and the  $\text{PbFBr}$  Bragg peaks can be followed simultaneously in real time (see Fig. 5c). Examples of such measurements, showing the changes in reflectivity at  $q_z = 0.75 \text{ \AA}^{-1}$  and in the intensity of the  $\text{PbFBr}(001)$  peak are presented in Fig 6, together with the parallel recorded current density transients. Control experiments where the potential is stepped to  $-0.80 \text{ V}$  (i.e. to potentials negative of the dealumination range) show no change in the reflectivity and no Bragg peaks. For jumps to  $-0.8 \text{ V}$  the formation of the precursor layer occurs on a very short time scales, as indicated by the increase of intensity of the specular component within 5 s. Subsequently, the reflectivity decreases linearly, to about two thirds of the initial intensity over the next 600 s. This process is accompanied by the appearance of the  $\text{PbFBr}$  Bragg peaks, which linearly increase in intensity over the same time period. Based on these observations, the  $\text{PbFBr}$  growth at this potential proceeds slow but continuously and at approximately constant rate. In contrast, at more positive potentials the Bragg peak intensity saturates after an initial rise, indicating self-limiting growth of a  $\text{PbFBr}$  film with a (potential-dependent) thickness of several ten nanometers. This suggests that the fast growth at higher potentials results in more dense films that subsequently block the vertical transport of ions and thus further film growth. In all experiments the  $\text{PbFBr}$  deposit rapidly dissolves after stepping the potential back into the potential regime of amalgamation and the specular reflectivity returned to the intensity characteristic for the clean Hg electrolyte interface.

## Conclusions

In this overview review article we demonstrated that the atomic-scale structure of liquid-liquid interfaces – one of the last frontiers in interface science – is now accessible to experimental studies. Key to this are surface scattering techniques employing X-ray radiation of high photon energy and utmost brilliance, available at modern synchrotron radiation sources, and dedicated instruments for studies of fluid interfaces. These methods have enabled real time *in situ* and *operando* investigations of these fascinating systems. Even the results on the small number of studies that have been

studied up to now reveal that liquid-liquid electrochemical interfaces exhibit by far more complex phenomena than previously anticipated. For the Hg - electrolyte interface discussed in this work the structural data indicate an atomically sharp interface where the liquid electrode is terminated by a well-defined close-packed layer of Hg atoms. However, the Hg surface structure depends pronouncedly on the potential, temperature and chemical environment. Furthermore, first studies of adsorption and deposition at this interface show surprising complexity, such as the formation of ultrathin crystalline layers between the two liquid phases. Clarifying whether such behaviour occurs also in other adsorbate systems and extending atomic-scale studies to other electrochemical liquid-liquid systems of current interest remains a task for future X-ray scattering studies.

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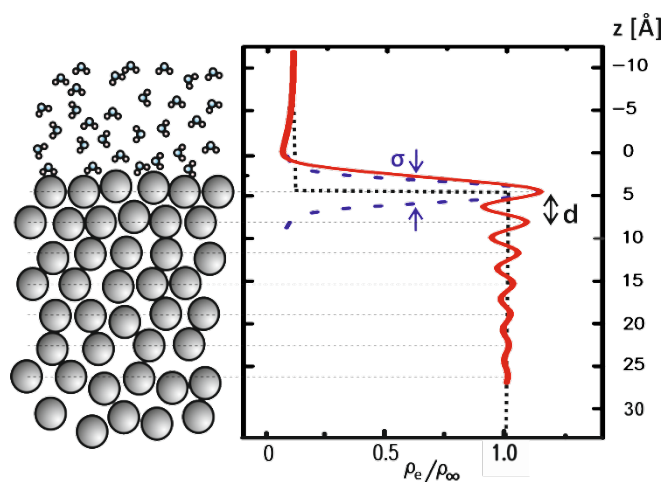
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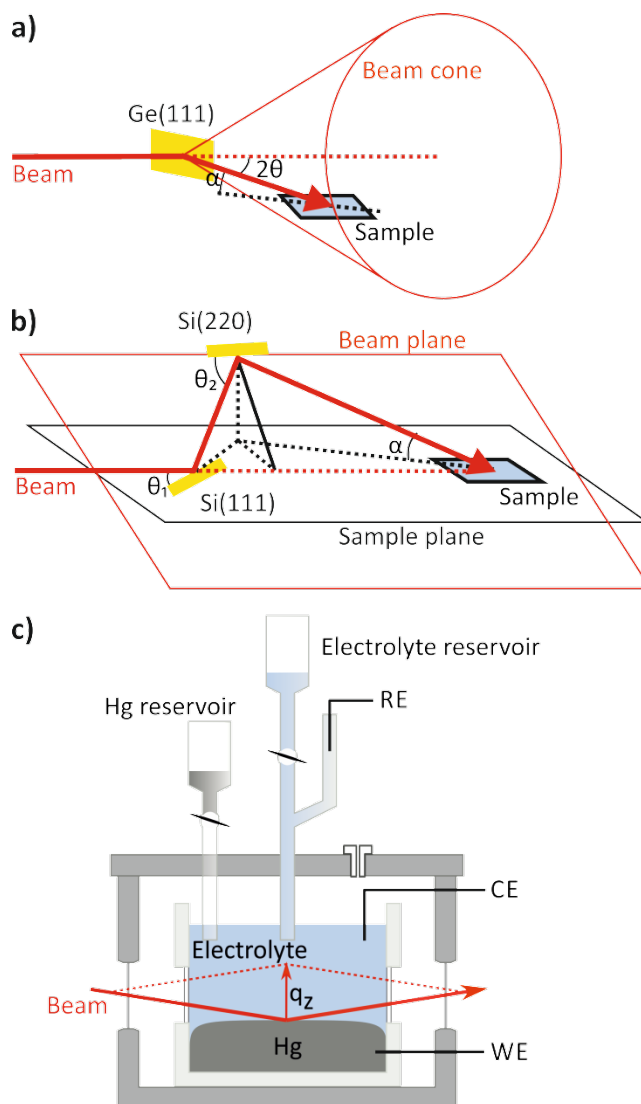
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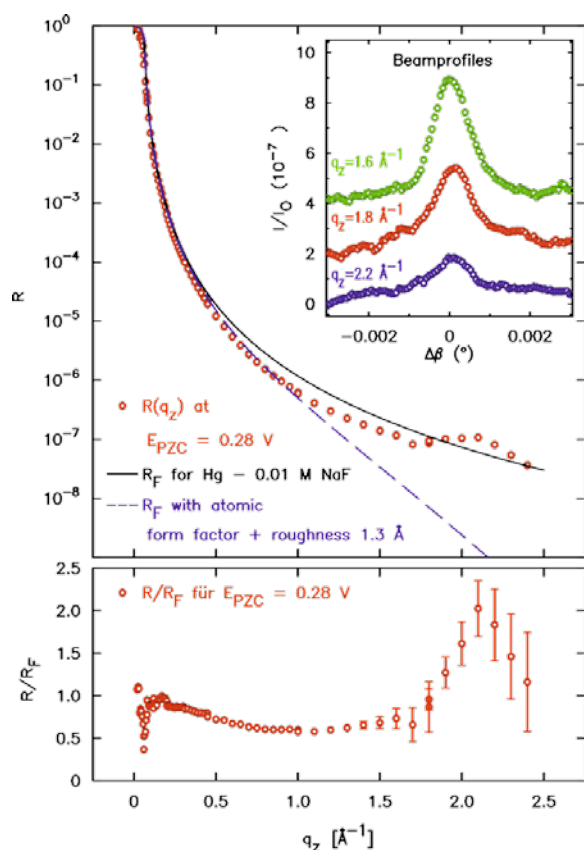
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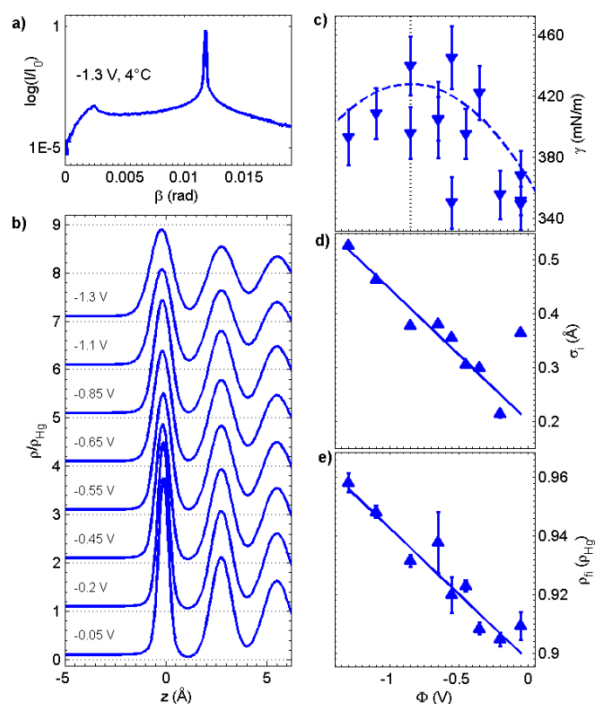
**Fig. 1** Atomic-scale structure and corresponding density profile of a liquid-liquid interface.



**Fig. 2** Liquid interface scattering geometry with a) a single deflecting crystal and b) a double crystal Bragg deflector. c) Electrochemical cell for X-ray scattering studies of liquid metal - electrolyte interfaces. The X-ray beam enters and leaves the cell through glass windows and passes through the bulk of the electrolyte solution before and after reflection at the Hg surface. The entire cell is kept in inert gas atmosphere to keep the electrolyte clean and free of oxygen.



**Fig. 3** (a) X-ray reflectivity of the interface between liquid Hg and 0.01 M NaF solution at a potential of 0.28 V relative to the potential of zero charge. In addition to the XRR data the Fresnel reflectivity  $R_F(q_z)$  of an ideal sharp interface and of an interface profile broadened by  $1.3 \text{ \AA}$  roughness and the Hg atomic form factor is shown. The peak at  $2.2 \text{ \AA}^{-1}$  indicates Hg surface layering. In the inset profiles of the reflected beam at selected  $q_z$  positions are displayed (measured at  $\phi = 0.05 \text{ V}$ ) (b) Fresnel normalized reflectivity curve of the XRR data (after Ref. 34).



**Fig. 4** Results of combined XRR and XDS measurements of liquid Hg in 0.01 M NaF. (a) Typical example of the diffuse scattering as a function of exit angle  $\beta$ , obtained at  $q_z = 0.9 \text{ \AA}^{-1}$ . (b) Extracted electron density profiles as a function of potential (for clarity the curves are offset by 1). The potential dependent (c) interfacial tension, (d) intrinsic width, common to all layers, and (e) density of the first Hg layer (relative to the density of bulk Hg) obtained from a quantitative analysis of the X-ray scattering data at  $4^\circ\text{C}$ . The blue dashed line in (c) corresponds to the electrocapillary curve reported in Ref. 66.

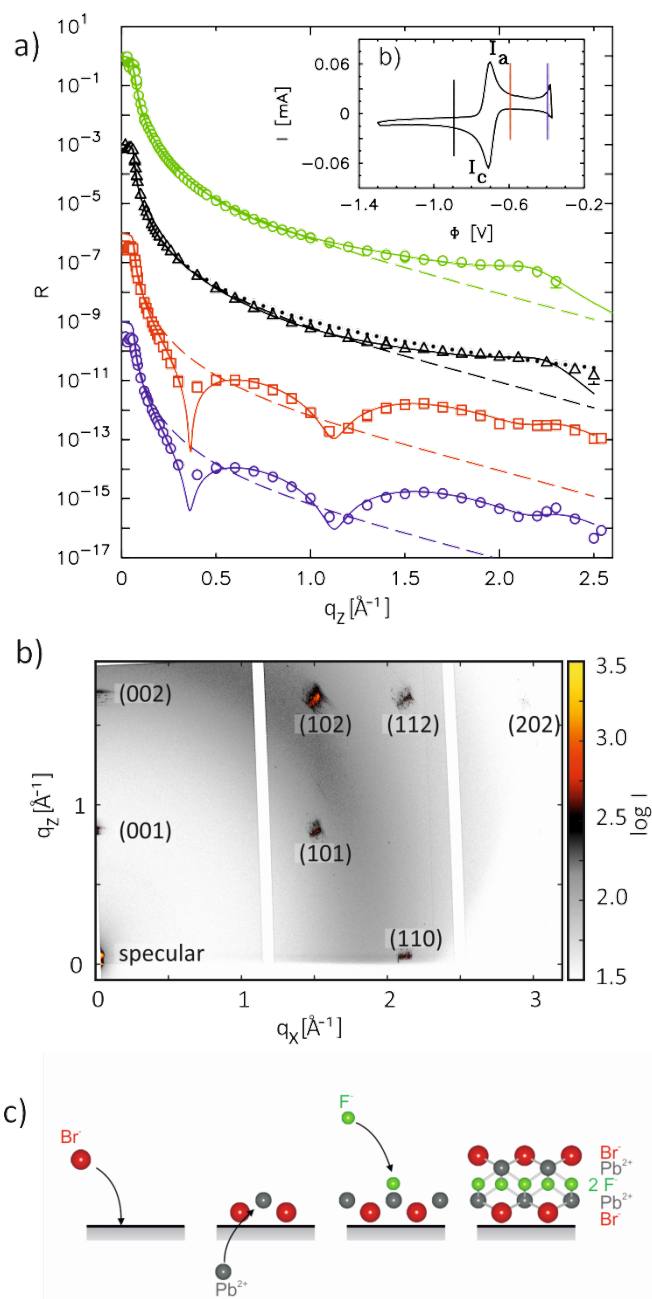
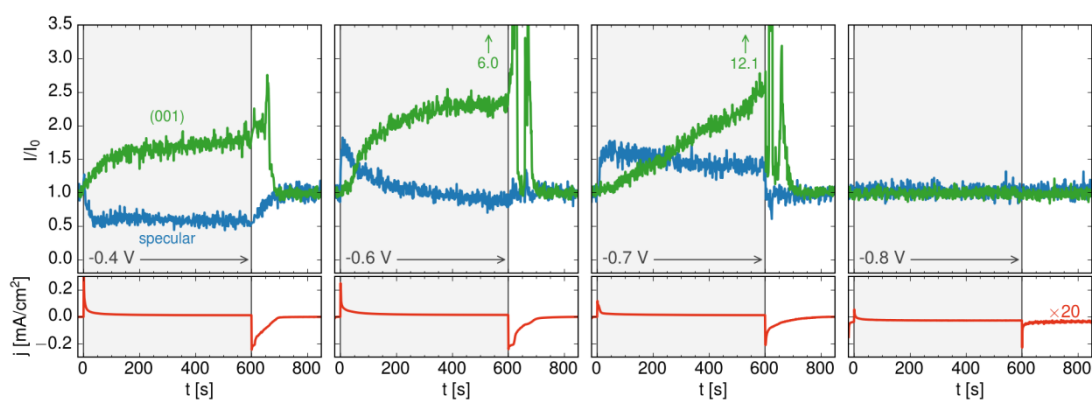


illustration of the formation of the PbBrF precursor layer (after Ref. 36).

**Fig. 5** *In situ* X-ray scattering studies of nucleation and growth on liquid Hg in 0.01 M NaF + 0.01M NaBr + 0.25 mM PbBr<sub>2</sub> solution. (a) Measured XRR curves at -0.90 V (black triangles), -0.60 V (red squares), and -0.40 V (blue circles) as well as an XRR curve measured at the Hg - 0.01 M NaF interface at -0.90 V (green circles). For clarity, the XRR curves are offset by a factor of  $10^{-3}$ . Solid lines correspond to the best fits by the models described in the text, the dashed lines to the reflectivity of an interface with a Gaussian roughness of  $\sigma = 1.00 \text{ \AA}$ . (b) Corresponding cyclic voltammogram (scan rate 5 mV/s), with vertical lines marking the potentials of the XRR measurements. (c) Intensity maps in the  $q_y$  -  $q_z$  plane measured at -0.60 V  $\alpha = 0.135^\circ$ , showing Bragg reflections from a thin film of crystalline PbBrF on the Hg surface. (d) Schematic



**Fig 6** Kinetic studies of PbFBr growth and dissolution on Hg in 0.01 M NaF + 0.01M NaBr + 0.25 mM PbBr<sub>2</sub> by *operando* X-ray scattering. Shown is the time dependent behaviour of the specular XRR signal at  $q_z = 0.9 \text{ \AA}^{-1}$ , (blue), of the PbFBr(001) Bragg peak (green) and of the simultaneously measured electrochemical current density (red) at four different potentials (after Ref. 36).

